NSN 5961-01-114-1350

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

Between 0.628 inches and 0.658 inches

Overall Height:

Between 0.120 inches and 0.150 inches

Overall Width:

Between 0.490 inches and 0.520 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

Between 4.00 amperes source cutoff current and 12.00 amperes source cutoff current

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release6353 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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